

RELIABILITY REPORT  
FOR  
MAX9157EGJ+  
PLASTIC ENCAPSULATED DEVICES

June 1, 2010

**MAXIM INTEGRATED PRODUCTS**

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## Conclusion

The MAX9157EGJ+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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### I. Device Description

#### A. General

The MAX9157 is a quad bus LVDS (BLVDS) transceiver for heavily loaded, half-duplex multipoint buses. Small 32-pin QFN and TQFP packages and flow-through pinouts allow the transceiver to be placed near the connector for the shortest possible stub length. The MAX9157 drives LVDS levels into a 27  $\Omega$  load (double terminated, heavily loaded LVDS bus) at up to 200Mbps. An input fail-safe circuit ensures the receiver output is high when the differential inputs are open, or undriven and shorted, or undriven and terminated. The MAX9157 differential inputs feature 52mV hysteresis for greater immunity to bus noise and reflections. The MAX9157 operates from a single 3.3V supply, consuming 80.9mA supply current with drivers enabled, and 22.7mA with drivers disabled. The MAX9157's high-impedance I/Os (except for receiver outputs) when VCC = 0 or open, combined with glitch-free power-up and power-down, allow hot swapping of cards in multicard bus systems; 7.2pF (max) BLVDS I/O capacitances minimize bus loading. The MAX9157 is offered in 5mm x 5mm 32-pin QFN and TQFP packages. The MAX9157 is fully specified for the -40°C to +85°C extended temperature range. Refer to the MAX9129 data sheet for a quad BLVDS driver, ideal for dual multipoint full-duplex buses.

## II. Manufacturing Information

A. Description/Function:	Quad Bus LVDS Transceiver
B. Process:	TS35
C. Number of Device Transistors:	
D. Fabrication Location:	Taiwan
E. Assembly Location:	Korea
F. Date of Initial Production:	January 26, 2002

## III. Packaging Information

A. Package Type:	32-pin QFN 5x5
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-2801-0032
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	47°C/W
K. Single Layer Theta Jc:	2.3°C/W
L. Multi Layer Theta Ja:	30°C/W
M. Multi Layer Theta Jc:	2.3°C/W

## IV. Die Information

A. Dimensions:	100 X 68 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	0.35μm
F. Minimum Metal Spacing:	0.35μm
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

- A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)  
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.  
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 80 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 13.7 \times 10^{-9}$$
$$\lambda = 13.7 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the TS35 Process results in a FIT Rate of 0.11 @ 25C and 1.93 @ 55C (0.8 eV, 60% UCL)

### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

### C. E.S.D. and Latch-Up Testing

The HS16 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250mA.

**Table 1**  
Reliability Evaluation Test Results

**MAX9157EGJ+**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
<b>Static Life Test</b> (Note 1)				
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	80	0
<b>Moisture Testing</b> (Note 2)				
HAST	Ta = 130°C RH = 85% Biased Time = 96hrs.	DC Parameters & functionality	77	0
<b>Mechanical Stress</b> (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data